<u>TOSHIBA</u>

查询"2SC1959_07" **做实摘**A Transistor Silicon PNP Epitaxial Type (PCT process)

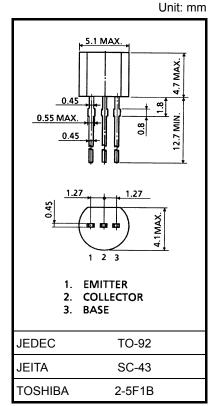
2SC1959

Audio Frequency Low Power Amplifier Applications Driver Stage Amplifier Applications Switching Applications

- Excellent hFE linearity: hFE (2) = 25 (min): VCE = 6 V, IC = 400 mA
- 1 watt amplifier applications.
- Complementary to 2SA562TM.

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage | V _{CBO} | 35 | V |
| Collector-emitter voltage | V _{CEO} | 30 | V |
| Emitter-base voltage | V _{EBO} | 5 | V |
| Collector current | Ι _C | 500 | mA |
| Base current | Ι _Β | 100 | mA |
| Collector power dissipation | P _C | 500 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature range | T _{stg} | -55~150 | °C |



Weight: 0.21 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|-------------------------------|--|-----|------|------|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = 35 V, I_E = 0$ | _ | | 0.1 | μA |
| Emitter cut-off current | I _{EBO} | $V_{EB} = 5 V, I_{C} = 0$ | _ | _ | 0.1 | μA |
| DC current gain | h _{FE (1)} (Note) | $V_{CE} = 1 \text{ V}, \text{ I}_{C} = 100 \text{ mA}$ | 70 | _ | 400 | |
| | h _{FE (2)} (Note) | $V_{CE} = 6 \text{ V}, \text{ I}_{C} = 400 \text{ mA}$ | 25 | _ | | |
| Collector-emitter saturation voltage | V _{CE (sat)} | $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$ | _ | 0.1 | 0.25 | V |
| Base-emitter voltage | V _{BE} | $V_{CE} = 1 \text{ V}, \text{ I}_{C} = 100 \text{ mA}$ | _ | 0.8 | 1.0 | V |
| Transition frequency | f _T | $V_{CE} = 6 \text{ V}, \text{ I}_{C} = 20 \text{ mA}$ | _ | 300 | _ | MHz |
| Collector output capacitance | C _{ob} | $V_{CB} = 6 V, I_E = 0, f = 1 MHz$ | _ | 7 | _ | pF |

Note: $h_{FE(1)}$ classification O: 70~140, Y: 120~240, GR: 200~400

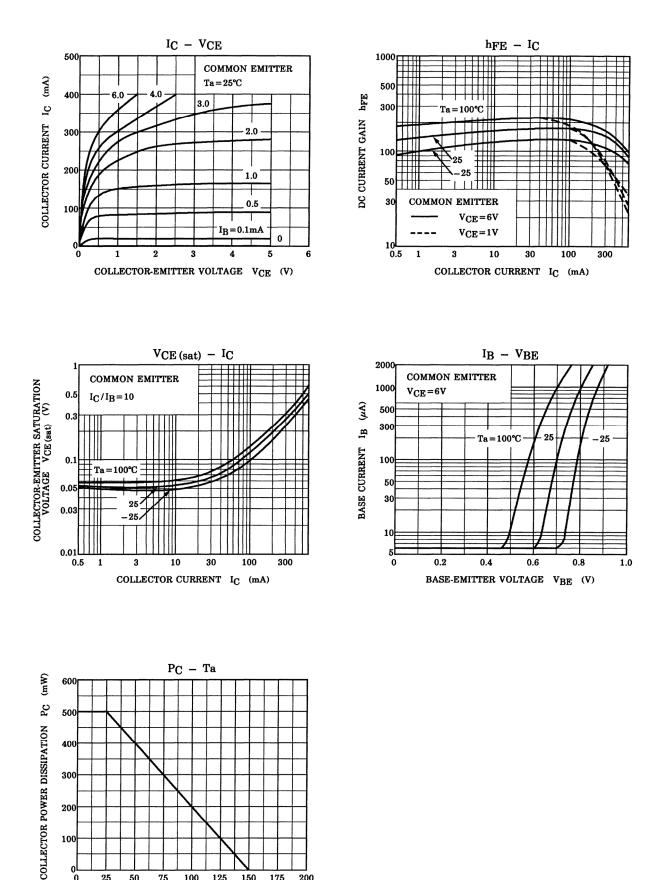
 $h_{FE\ (2)}$ classification O: 25 (min), Y: 40 (min)

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AMBIENT TEMPERATURE Ta (°C)



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RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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